

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE01ND03S uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =100V,I_D =3A

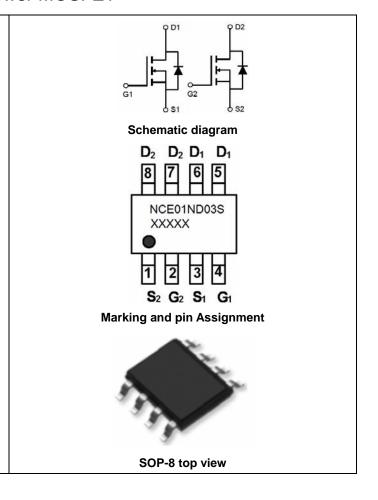
 $R_{DS(ON)}$ < 130m Ω @ V_{GS} =10V

 $R_{DS(ON)}$ < 140m Ω @ V_{GS} =4.5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE01ND03S	NCE01ND03S	SOP-8	Ø330mm	12mm	4000 units

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

About the maximum realings (TA-20 Camboo Cambridge Mos Hotoa)					
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V _{DS}	100	V		
Gate-Source Voltage	V _G s	±20	V		
Drain Current-Continuous	I _D	3	А		
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	2.1	А		
Pulsed Drain Current ^(Note 1)	I _{DM}	12	Α		
Maximum Power Dissipation	P _D	2	W		
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}$ C		

Thermal Characteristic

Parameter	Symbol	Тур	Max	Unit
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	62.5	85	°C/W



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Electrical Characteristics (T_A=25 ℃ unless otherwise noted)

Symbol	Condition	Min	Тур	Max	Unit
		•			
e BV _{DSS} V_{GS} =0V I_D =250 μ A		100	110	-	V
I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μA
I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
		•			
V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	1.0	1.5	2.0	V
R _{DS(ON)}	V _{GS} =10V, I _D =3A	-	95	130	mΩ
	V _{GS} =4.5V, I _D =3A		100	140	
g FS	V _{DS} =5V,I _D =3A	3.5	-	-	S
C _{lss}	\/ -50\/\/ -0\/	-	730	-	PF
Coss		-	37	-	PF
C _{rss}	F = 1.0WII 12	-	27	-	PF
t _{d(on)}		-	11	-	nS
t _r	V_{DD} =50V, R_L =15 Ω	-	7.4	-	nS
$t_{d(off)}$	V_{GS} =10 V , R_{G} =2.5 Ω	-	35	-	nS
t _f		-	9.1	-	nS
Q_g	\/ _F0\/ L _2A	-	21.5		nC
Q_{gs}	, ,	-	3.2	-	nC
Q_{gd}	V _{GS} -10V	-	6	-	nC
V _{SD}	V _{GS} =0V,I _S =3A	-	-	1.2	V
Is		-	-	3	Α
t _{rr}	TJ = 25°C, I _F =3A	-	26		nS
Qrr	di/dt = 100A/µs ^(Note3)	-	27		nC
	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				
	BVDSS IDSS IDSS IGSS VGS(th) RDS(ON) GFS Clss Coss Crss td(on) tr td(off) tf Qg Qgs Qgd VSD IS trr	$ \begin{array}{ c c c c } \hline BV_{DSS} & V_{GS} = 0V \ I_D = 250 \mu A \\ \hline I_{DSS} & V_{DS} = 100 V, V_{GS} = 0V \\ \hline I_{GSS} & V_{GS} = \pm 20 V, V_{DS} = 0V \\ \hline \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu A \\ \hline V_{GS} = 10 V, \ I_D = 3A \\ \hline V_{GS} = 4.5 V, \ I_D = 3A \\ \hline V_{DS} = 5 V, I_D = 3A \\ \hline \hline C_{ISS} & V_{DS} = 5 V, V_{GS} = 0V, \\ \hline C_{CSS} & F = 1.0 MHz \\ \hline \hline t_{d(on)} & V_{DD} = 50 V, R_L = 15 \Omega \\ \hline V_{GS} = 10 V, R_G = 2.5 \Omega \\ \hline t_f & V_{DS} = 50 V, I_D = 3A, \\ \hline V_{GS} = 10 V, R_G = 2.5 \Omega \\ \hline \hline V_{GS} = 10 V \\ \hline V_{GS} = 10 V \\ \hline \hline V_{SD} & V_{GS} = 0 V, I_S = 3A \\ \hline I_S & \\ \hline I_{TT} & TJ = 25 ^{\circ} C, I_F = 3A \\ \hline \end{array} $	$ \begin{array}{ c c c c c } \hline \textbf{Symbol} & \textbf{Condition} & \textbf{Min} \\ \hline & \textbf{BV}_{DSS} & \textbf{V}_{GS} = 0 \textbf{V} \ \textbf{I}_{D} = 250 \mu \textbf{A} & 100 \\ \hline & \textbf{I}_{DSS} & \textbf{V}_{DS} = 100 \textbf{V}, \textbf{V}_{GS} = 0 \textbf{V} & - \\ \hline & \textbf{I}_{GSS} & \textbf{V}_{GS} = \pm 20 \textbf{V}, \textbf{V}_{DS} = 0 \textbf{V} & - \\ \hline & \textbf{V}_{GS} & \textbf{V}_{DS} = 250 \mu \textbf{A} & 1.0 \\ \hline & \textbf{V}_{DS} = \textbf{V}_{QS}, \textbf{I}_{D} = 250 \mu \textbf{A} & - \\ \hline & \textbf{V}_{GS} = 10 \textbf{V}, \ \textbf{I}_{D} = 3 \textbf{A} & - \\ \hline & \textbf{V}_{DS} = 50 \textbf{V}, \textbf{I}_{D} = 3 \textbf{A} & 3.5 \\ \hline & \textbf{C}_{ISS} & \textbf{V}_{DS} = 50 \textbf{V}, \textbf{V}_{GS} = 0 \textbf{V}, \\ \hline & \textbf{C}_{COSS} & \textbf{F} = 1.0 \textbf{MHz} & - \\ \hline & \textbf{C}_{ISS} & \textbf{V}_{DD} = 50 \textbf{V}, \ \textbf{R}_{L} = 15 \Omega & - \\ \hline & \textbf{t}_{I} & \textbf{V}_{DS} = 50 \textbf{V}, \textbf{I}_{D} = 3 \textbf{A}, \\ \hline & \textbf{V}_{DS} = 50 \textbf{V}, \textbf{I}_{D} = 3 \textbf{A}, \\ \hline & \textbf{V}_{QS} = 10 \textbf{V} & - \\ \hline & \textbf{V}_{QS} = 10 \textbf{V} & - \\ \hline & \textbf{V}_{SD} & \textbf{V}_{GS} = 0 \textbf{V}, \textbf{I}_{S} = 3 \textbf{A} & - \\ \hline & \textbf{I}_{S} & - \\ \hline & \textbf{I}_{S} & - \\ \hline & \textbf{I}_{Tr} & \textbf{TJ} = 25 ^{\circ} \textbf{C}, \ \textbf{I}_{F} = 3 \textbf{A} & - \\ \hline \end{array}$	$ \begin{array}{ c c c c c c c } \hline \textbf{Symbol} & \textbf{Condition} & \textbf{Min} & \textbf{Typ} \\ \hline & \textbf{BV}_{DSS} & \textbf{V}_{GS}=0 \textbf{V} \textbf{ I}_{D}=250 \mu A & 100 & 110 \\ \hline & \textbf{I}_{DSS} & \textbf{V}_{DS}=100 \textbf{V}, \textbf{V}_{GS}=0 \textbf{V} & - & - \\ \hline & \textbf{I}_{GSS} & \textbf{V}_{GS}=\pm 20 \textbf{V}, \textbf{V}_{DS}=0 \textbf{V} & - & - \\ \hline & \textbf{V}_{GS}(\text{Ih}) & \textbf{V}_{DS}=\textbf{V}_{GS}, \textbf{I}_{D}=250 \mu A & 1.0 & 1.5 \\ \hline & \textbf{V}_{GS}=10 \textbf{V}, \textbf{I}_{D}=3 A & - & 95 \\ \hline & \textbf{V}_{GS}=10 \textbf{V}, \textbf{I}_{D}=3 A & - & 95 \\ \hline & \textbf{V}_{DS}=5 \textbf{V}, \textbf{I}_{D}=3 A & 3.5 & - \\ \hline & \textbf{C}_{ISS} & \textbf{V}_{DS}=5 \textbf{V}, \textbf{V}_{GS}=0 \textbf{V}, \\ \hline & \textbf{C}_{COSS} & \textbf{F}=1.0 \textbf{MHz} & - & 730 \\ \hline & \textbf{C}_{CISS} & \textbf{V}_{DS}=50 \textbf{V}, \textbf{V}_{GS}=0 \textbf{V}, \\ \hline & \textbf{T}_{I} & \textbf{V}_{DD}=50 \textbf{V}, \textbf{R}_{L}=15 \Omega & - & 7.4 \\ \hline & \textbf{V}_{DS}=10 \textbf{V}, \textbf{R}_{G}=2.5 \Omega & - & 35 \\ \hline & \textbf{T}_{I} & \textbf{V}_{DS}=50 \textbf{V}, \textbf{I}_{D}=3 \textbf{A}, \\ \hline & \textbf{V}_{QS} & \textbf{V}_{DS}=50 \textbf{V}, \textbf{I}_{D}=3 \textbf{A}, \\ \hline & \textbf{V}_{QS}=10 \textbf{V} & - & 6 \\ \hline & \textbf{V}_{SD} & \textbf{V}_{GS}=0 \textbf{V}, \textbf{I}_{S}=3 A & - & - \\ \hline & \textbf{I}_{S} & - & - $	$ \begin{array}{ c c c c c c c c } \hline \textbf{Symbol} & \textbf{Condition} & \textbf{Min} & \textbf{Typ} & \textbf{Max} \\ \hline \textbf{BV}_{DSS} & \textbf{V}_{GS}=0\textbf{V} \textbf{ I}_{D}=250\mu \textbf{A} & 100 & 110 & - \\ \hline \textbf{I}_{DSS} & \textbf{V}_{DS}=100\textbf{V}, \textbf{V}_{GS}=0\textbf{V} & - & - & 1 \\ \hline \textbf{I}_{GSS} & \textbf{V}_{GS}=\pm20\textbf{V}, \textbf{V}_{DS}=0\textbf{V} & - & - & \pm100 \\ \hline \textbf{V}_{GS(th)} & \textbf{V}_{DS}=\textbf{V}_{GS}, \textbf{I}_{D}=250\mu \textbf{A} & 1.0 & 1.5 & 2.0 \\ \hline \textbf{R}_{DS(ON)} & \textbf{V}_{OS}=10\textbf{V}, \textbf{I}_{D}=3\textbf{A} & - & 95 & 130 \\ \hline \textbf{V}_{GS}=10\textbf{V}, \textbf{I}_{D}=3\textbf{A} & - & 95 & 130 \\ \hline \textbf{V}_{DS}=5\textbf{V}, \textbf{I}_{D}=3\textbf{A} & 100 & 140 \\ \hline \textbf{J}_{DS}=5\textbf{V}, \textbf{J}_{D}=3\textbf{A} & 3.5 & - & - \\ \hline \textbf{C}_{ISS} & \textbf{V}_{DS}=5\textbf{V}, \textbf{V}_{GS}=0\textbf{V}, \\ \hline \textbf{C}_{OSS} & \textbf{F}=1.0\textbf{MHz} & - & 730 & - \\ \hline \textbf{C}_{ISS} & \textbf{V}_{DS}=5\textbf{V}, \textbf{V}_{GS}=0\textbf{V}, \\ \hline \textbf{F}=1.0\textbf{MHz} & - & 27 & - \\ \hline \textbf{J}_{I} & - & 27 & - \\ \hline \textbf{J}_{I} & - & - & 35 & - \\ \hline \textbf{J}_{I} & - & - & 3.2 & - \\ \hline \textbf{Q}_{g} & \textbf{V}_{DS}=5\textbf{OV}, \textbf{I}_{D}=3\textbf{A}, \\ \textbf{V}_{GS}=1\textbf{OV}, \textbf{I}_{S}=3\textbf{A} & - & - & 1.2 \\ \hline \textbf{I}_{S} & - & - & 3 & - & - \\ \hline \textbf{I}_{S} & - & - & 3 & - \\ \hline \textbf{I}_{S} & - & - & 3 & - \\ \hline \textbf{I}_{S} & - & - & 3 & - & - \\ \hline \textbf{J}_{SD} & \textbf{V}_{GS}=0\textbf{V}, \textbf{I}_{S}=3\textbf{A} & - & - & 1.2 \\ \hline \textbf{I}_{S} & - & - & 3 & - & - & 3 \\ \hline \textbf{I}_{IT} & \textbf{TJ}=25^{\circ}\textbf{C}, \textbf{I}_{F}=3\textbf{A} & - & 26 \\ \hline \end{tabular} $

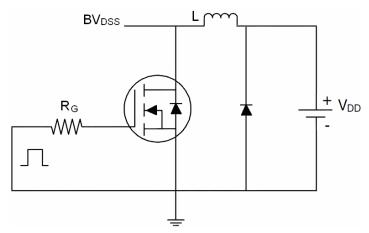
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. The value of R $_{\text{BJA}}$ is measured with the device mounted on 1in 2 FR-4 board with 2oz. Copper, in a still air environment with T $_{\text{A}}$ =25°C. The value in any given application depends on the user's specific board design. Surface Mounted on FR4 Board, t \leq 10 sec. The current rating is based on the t \leq 10s thermal resistance rating.
- 3. Pulse Test: Pulse Width ≤ $300\mu s$, Duty Cycle ≤ 2%.
- $\textbf{4.} \ \textbf{Guaranteed by design, not subject to production} \ .$

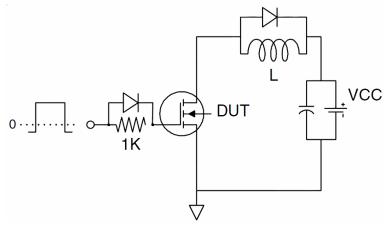


Test Circuit

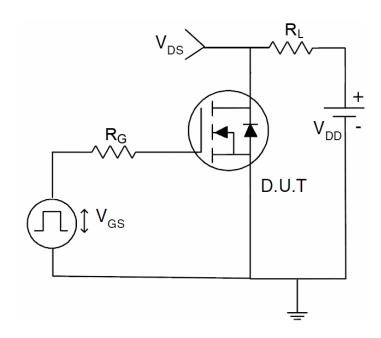
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit:



3) Switch Time Test Circuit:





N-channel Typical Electrical and Thermal Characteristics (Curves)

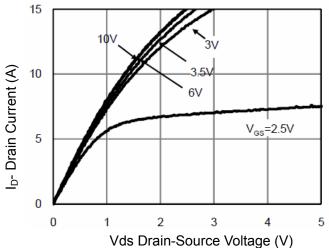


Figure 1 Output Characteristics

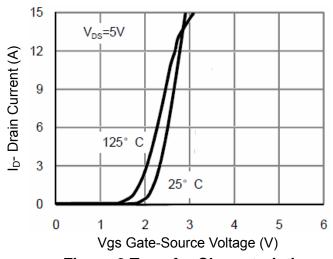


Figure 2 Transfer Characteristics

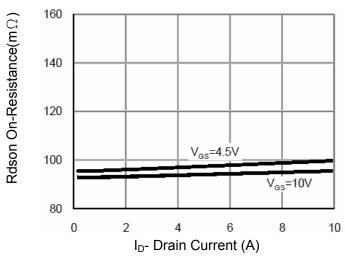


Figure 3 Rdson- Drain Current

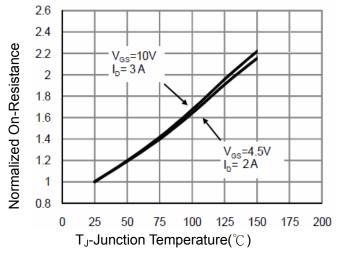


Figure 4 Rdson-Junction Temperature

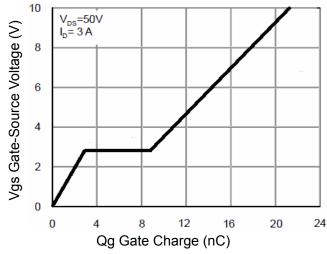


Figure 5 Gate Charge

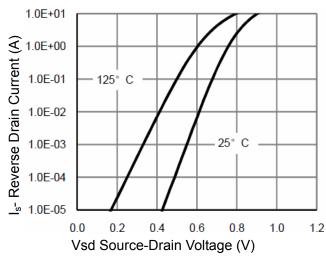
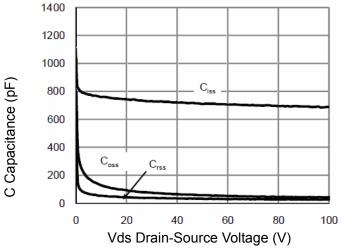


Figure 6 Source- Drain Diode Forward

200





Power Dissipation (W) 0.8 0.4 0 0 25 100 125 150 175 75

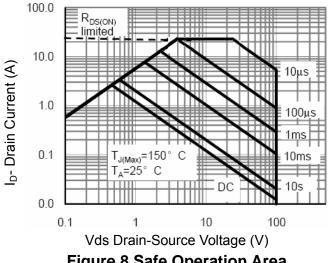
2

1.6

1.2

Figure 7 Capacitance vs Vds

T_J-Junction Temperature(°C) Figure 9 Power De-rating



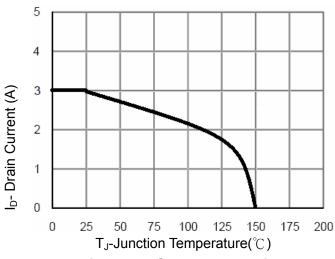
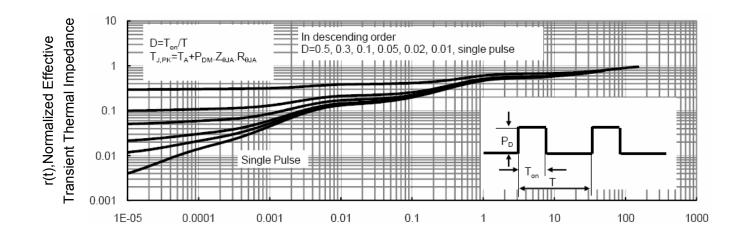


Figure 8 Safe Operation Area

Figure 10 Current De-rating

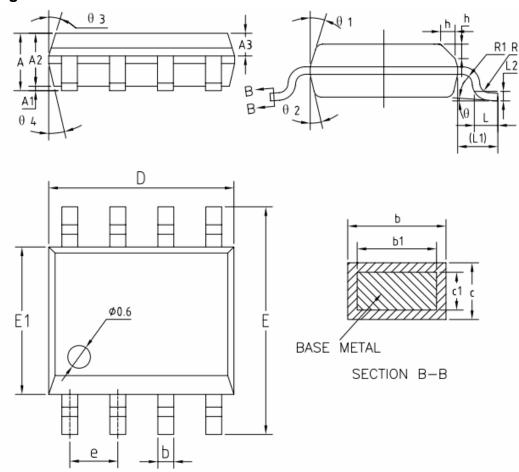


Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



SOP-8 Package Information



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX	
Α	1.35	1.55	1.75	
A1	0.10	0.15	0.25	
A2	1.25	1.40	1.65	
A3	0.50	0.60	0.70	
b	0.38	_	0.51	
b1	0.37	0.42	0.47	
С	0.18	_	0.25	
c1	0.17	0.20	0.23	
D	4.80	4.90	5.00	
E	5.80	6.00	6.20	
E1	3.80	3.90	4.00	
е	1.17	1.27	1.37	
L	0.45	0.60	0.80	
L1	1.04REF			
L2	0.25BSC			
R	0.07	_	-	
R1	0.07	_	_	
h	0.30	0.40	0.50	
θ	0.	_	8*	
θ 1	15 *	17°	19 °	
θż	11*	13 °	15°	
θ 3	15 *	17*	19 °	
θ 4	11*	13°	15 °	



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